

Title (en)  
CAPACITOR ELEMENT WITH ELECTRODE SURFACE PATTERN FOR CAPACITIVE MEASURING SENSORS.

Title (de)  
KONDENSATORELEMENT MIT ELEKTRODENFLÄCHEN-MUSTER FÜR KAPAZITIVE MESSWERTGEBER.

Title (fr)  
ELEMENT CONDENSATEUR A AGENCEMENTS D'ELECTRODES DE SURFACE POUR CAPTEURS DE MESURES.

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Application  
**EP 88905175 A 19880623**

Priority  
CH 244687 A 19870629

Abstract (en)  
[origin: WO8900277A1] The invention concerns capacitor elements with electrode surface patterns in which the electrode surfaces (11) are free of contact holes and are applied to a substrate layer (13) with pre-existing contacting holes (12). The tracks (14) pass through the contacting holes (12) in the substrate layer (13) onto the other side of the substrate layer (13) and are connected to the electrode surfaces (11).

Abstract (de)  
Kondensatorelemente mit Elektrodenflächen-Mustern, wobei die Elektrodenfläche (11) kontaktlöcherfrei sind und auf eine Substratschicht (13) mit vorgefertigten Kontaktierungslöchern (12) aufgebracht sind. Auf der anderen Seite der Substratschicht (13) sind die Leiterbahnen (14) durch die Kontaktierungslöcher (12) in der Substratschicht (13) hindurch aufgebracht und mit den Elektrodenflächen (11) verbunden. Abstract The invention concerns capacitor elements with electrode surface patterns in which the electrode surfaces (11) are free of contact holes and are applied to a substrate layer (13) with pre-existing contacting holes (12). The tracks (14) pass through the contacting holes (12) in the substrate layer (13) onto the other side of the substrate layer (13) and are connected to the electrode surfaces (11).

Abstract (fr)  
Dans des éléments condensateurs à agencements d'électrodes de surface, la surface des électrodes (11) est dépourvue d'orifices de contact et est montée sur une couche de substrat (13) pourvue d'orifices de contact (12) préfabriqués. Les pistes conductives (14) montées de l'autre côté de la couche de substrat (13) traversent les orifices de contact (12) de la couche de substrat (13) et sont reliées aux électrodes de surface (11).

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